Band Theory of Solids

Formation of Energy Bands

In solids, a periodic potential is formed by the nucleus and other electron cloud. Motion of an electron in periodic potential can be represented by Schrödinger equation, whose solution gives energy states. These states are filled with electrons according to Pauli's exclusion principle & all clates are not accessible but bands of energies separated by forbidden energies are possible.

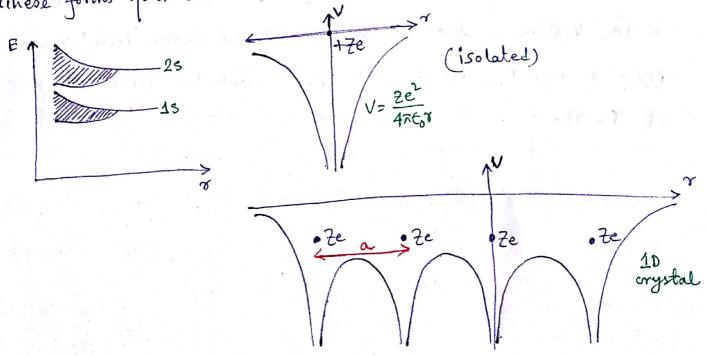
when two alons are brought close, single energys level splits into a pair of levels. If 4, & 42 are

electronic wave functions, then due to overlag, resultant wave function

& (4, ± 42). For symmetric case, elsetron can remain midway to A-B but for antisymmetric it cannot, so there

à a difference in energy between (4,+42) & (4,-42).

Semilarly when N no. of atoms are brought together, each energy state splits into N energy states whose separation is very small. These forms quasicontinuous energy band.



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Origin of band structure This can be understood from nearly free electron model where electrons move in a periodic kernel in 1D. Energy of a free electron $E_k = \frac{t_1^2 k^2}{2m} \int_{-\infty}^{\infty} \psi_k(x) = e^{ikx}$ Low energy electrons can freely travel as their 2>> a. High energy electrons almost near to fermi energy home 2 Na, & suffer diffraction like X-rays in crystal surface. Electron with de Brighte

wavelength 2 is brags reflected, 2a cint = n2. or $K = \frac{2\pi}{\lambda}$ after substitution. $K = \pm \frac{n\pi}{a \sin \theta}$. For 1D

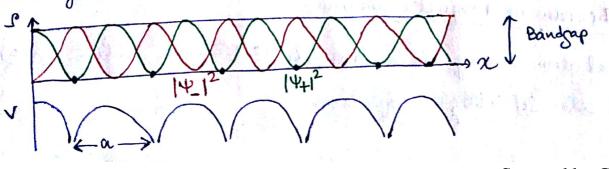
lattice $0 = \sqrt{2}$ or $K = \pm \frac{n\pi}{\alpha}$.

Thus a line representing K values $\frac{37a}{37a} - \frac{27a}{37a} - \frac{7}{38}$ o $\frac{27a}{37a}$ so divided by energy discontinuities into segments of length $\pm \frac{7}{4}$ which are the Brillouin zones.

At the boundary $K = \pm \frac{\pi}{a}$, electron wavefunctions are not traveling waves e it la le e it la but are standing waves, due to reflection. Two types of standing wave can form

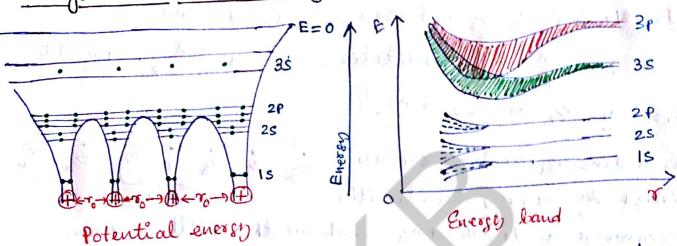
$$\Psi_{+} = e^{i\pi \frac{\gamma}{4}} + e^{-i\pi \frac{\gamma}{4}} = 2\cos\left(\frac{\pi \frac{\gamma}{\alpha}}{\alpha}\right) \left[\chi_{-} - \chi_{+} + \psi_{+} + \psi_{+} + \psi_{-} +$$

In quantum mechanics, probability density of electron is so that electron = $\psi^*\psi$ and for broweling wave $\psi = e^{\pm ikx}$, s=1 so that electron darge density $e_1\psi_1^2 = constant$. However for standing wave, darge density isn't constant but el41 & cos2(xx), e14-12 & sin2(xx)



for $\chi=0$, α , 2α , ... $\cos^2\frac{\pi\chi}{\alpha}=1$, so its maximum at the kernel core and thus negative election charge density lowering P.F. of Kernel. For $\chi=\frac{\alpha}{2},\frac{3\alpha}{2},...$, sint $\frac{\pi\chi}{\alpha}=1$, so its maximum in midway between kernel Δ increasing the P.F. w.r.t. to travelling wave. So Eq is the difference of two energies.

Energy bands in Sodium crystal



Valence orbital overlap for 35 orbital to form quasi continuous energy band. Emply 3P level also spreads, so as 25 l 2P with decrease of τ . When $\tau = \tau_0 = 0.367$ nm, 35 l 3P states overlap.

In metals, band overlap tappens but in other materials they are separated by a band gap Eg & the energy of highest filled level is Fermi energy Ef. At OK, Levels upto Ef is filled & those above are emply. Using Pauli's principle, each stand having N atoms can accomodate 2N electrons. If highest S-band is fully filled then electron drift using external force is stopped & such solids are called insulators.

Bloch Theorem or Floquet's theorem

for an electron moving in a 1D potential with V(X) = V(X+A) is given by the Schrödinger equation

 $\frac{d\Psi}{dx^2} + \frac{2m}{h^2} \left[E - V(x) \right] \Psi = 0$. Bloch theorem state that the solution of the Schrödinger equation for a periodic potential is $\psi(x) = e^{\pm ikx} u_k(x)$ where $u_k(x) = u_k(x+a)$, which are plane waves e tikk modulated by uk (x) with the periodicity of the lattice. You is the Bloch wave or Bloch function. Proof of Bloch's theorem If f(n) and g(x) are two real, independent solution of Schrödinger equation $\psi(\alpha) = Af(\alpha) + Bg(\alpha)$. As $V(\alpha) = V(\alpha+\alpha)$, f(x+a) and g(x+a) are also solutions. $f(x+a) = \alpha_1 f(x) + \alpha_2 g(x), \quad g(x+a) = \beta_1 f(x) + \beta_2 g(x).$ $\psi(\alpha+\alpha) = Af(\alpha+\alpha) + Bg(\alpha+\alpha)$ $= (A\alpha_1 + B\beta_1)f(x) + (A\alpha_2 + B\beta_2)g(x)$ = aAf(a) + aBg(a) = a y(a). where we have chosen $Ad_1 + B\beta_1 = AA$, $Ad_2 + B\beta_2 = AB$. with A a constant. Now this gives nonzero values of A and B if determinant of $\begin{vmatrix} x_{1} - \lambda & \beta_{1} \\ x_{2} & \beta_{2} - \lambda \end{vmatrix} = 0 \text{ or } \lambda^{2} - (x_{1} + \beta_{2})\lambda + \\ x_{1}\beta_{2} - x_{2}\beta_{1} = 0$ coefficient à zero [As f(a) & g(a) are solution of Sehrödinger equation. $\frac{2d^{2}f(x)}{dx^{2}} + \frac{2m}{h^{2}} \left[E - V(x) \right] f(x) = 0^{2}, \quad \frac{2d^{2}g(x)}{dx^{2}} + \frac{2m}{h^{2}} \left[E - V(x) \right] g(x)^{2} = 0$ Cultivact gwx - 1 . Subtract $f(x) \frac{d^2g(x)}{dx^2} - g(x) \frac{d^2g(x)}{dx^2} = 0 \text{ or } f(x) \frac{dg(x)}{dx} - g(x) \frac{df(x)}{dx} = contain$ coronellian = w(x)

= $f(x+\alpha) \left[\beta_1 \frac{df(x)}{dx} + \beta_2 \frac{dg(x)}{dx} \right] - g(x+\alpha) \left[\alpha_1 \frac{df(x)}{dx} + \alpha_2 \frac{dg(x)}{dx} \right]$

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= $\left[\alpha_1 f(\alpha) + \alpha_2 g(\alpha)\right] \left[\beta_1 \frac{df(\alpha)}{dx} + \beta_2 \frac{dg(\alpha)}{dx}\right] - \left[\beta_1 f(\alpha) + \beta_2 g(\alpha)\right] \left[\alpha_1 \frac{df(\alpha)}{dx} + \alpha_2 \frac{dg(\alpha)}{dx}\right]$ $= (\alpha_1\beta_2 - \alpha_2\beta_1) \left[f(\alpha) \frac{dg(\alpha)}{dn} - g(\alpha) \frac{df(\alpha)}{dn} \right] = (\alpha_1\beta_2 - \alpha_2\beta_1) W(\alpha)$ But W(x+a) = W(x) = constant, $o = \alpha_1 \beta_2 - \alpha_2 \beta_1 = 1$ Eq. (1) becomes, $\lambda^2 - (\alpha_1 + \beta_2) \lambda + 1 = 0$. Here $\alpha_1 + \beta_2$ is a function

of energy E & we have two roots A, & Az or two functions $\psi_1(x)$ and $\psi_2(x)$ with $\psi_1(x+a) = \lambda \psi(x) + \lambda_1 \lambda_2 = 1$.

Special cases $(x_1 + \beta_2)^2 \angle 4$, $x_2^2 - (d_1 + \beta_2) A + 1 = 6$ have complex roots, I conjugate to each other. $x_1 = e^{\pm ika}$ $x_2 = e^{\pm ika}$ $x_3 = e^{\pm ika}$ $x_4 = e^{\pm ika}$ $= e^{\pm ik(x+a)} u_k(x+a) = e^{\pm ika} u_k(x+a) = e^{\pm ika} u_k(x+a) = e^{\pm ika}$ = 24(2) Bloch theorem hence proved.

Special cases $(\alpha_1 + \beta_2)^2 > 1$, $\beta^2 - (\alpha_1 + \beta_2) + 1 = 0$ have real roots n. = eha, 2 = eha, h= real. & & corresponding Schrödinger equation, $\psi_1(x) = e^{\mu x} u(x)$, $\psi_2(x) = e^{-\mu x} u(x)$

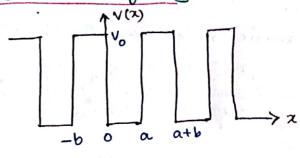
Although mathematically valid, these are forbidden wavefunctions as they're not bounded. at Id, both diverge.

The allowed roots etika and forbidder roots etha are functions of (d,+ b2) and hence energy. So energy spectrum of electron moving in periodic potential consists of allowed & forbidden energy regions orbands.

Kronig-Penny Model [Energy spectrum of electron consists of a

allowed energy bounds separated by forbidden region]

In free electron theory the assumption is valence electrons see zero potential but this isn't true with somice covalent bond as electrons are localized near



the nuclei, that gives periodically varying potential. Will

whose solution from Schrödinger equation is very hard.

Instead Kronig & Penny solved it using simples 1D potential of sharp end edge with periodicity a+b. V=0, 0< x < a whose Schrödinger equation is $= V_0$, -b< x < a

$$\frac{d^{2}\psi}{dx^{2}} + \frac{2m}{\frac{1}{2}} E\psi = 0, \quad 0 < x < \alpha$$

$$\frac{d^{2}\psi}{dx^{2}} + \frac{2m}{\frac{1}{2}} (E - V_{0})\psi = 0, \quad -b < x < 0$$

$$\frac{d^{2}\psi}{dx^{2}} + \frac{2m}{\frac{1}{2}} (E - V_{0})\psi = 0, \quad -b < x < 0$$

According to Bloch theorem, solution of wave equation for periodicity. $\Psi(x) = u_{K}(x) e^{iKx}$ with $u_{K}(x) = u_{K}(x+a+b)$.

By substituting was in equation 1 and substituting the boundary condition: $(u_1)_{n=0} = (u_2)_{n=0}$ $(u_1)_{n=0} = (u_2)_{n=0}$

$$\left(\frac{du_1}{dx}\right)_{x=0} = \left(\frac{du_2}{dx}\right)_{x=0} \left(\frac{du_1}{dx}\right)_{x=a} = \left(\frac{du_2}{dx}\right)_{x=b}$$

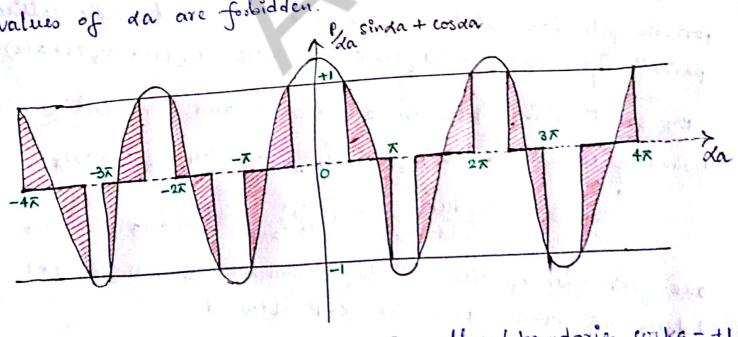
one gets four equations & to get nonzero coefficients the 4×4 determinant vanish. From that K-P obtained,

 $\frac{\beta^2 + \alpha^4}{2\alpha\beta}$ sinh βb sin $\alpha a + \cosh \beta b$ cos $\alpha = \cos k(\alpha + b)$

To simplify K-P considered when $V_0 \rightarrow \infty$ and $b \rightarrow 0$, $V_0 b$ is finite or potential barriers become S. functions. $V_0 b$ is known as barrier strength. As $b \rightarrow 0$, sinh $\beta b \rightarrow \beta b$, which $\beta b \rightarrow 1$ and $\frac{\rho^2 + \alpha^2}{2\alpha p} = \frac{mV_0}{\alpha p h^2} \qquad \stackrel{\circ}{=} \frac{mV_0 b}{\alpha h^2} \sin \alpha \alpha + \cos \alpha \alpha = \cos k\alpha$ $\frac{\rho}{4\alpha} = \frac{sind\alpha}{4\alpha} + \cos \alpha \alpha = \cos k\alpha \qquad \text{where } \rho = \frac{mV_0 ab}{h^2}$

when ρ is increased, the area of potential bornier is increased and the electron is bound more strongly to a potential well. $\rho \to 0$ means barrier is very weak f the electron become free electron $\rho \to 0$ means barrier is very weak f the electron become f electron $\rho \to 0$ him, $\rho \to 0$, $\rho \to 0$, $\rho \to 0$, $\rho \to 0$

As cos ka is bound between +1 and -1, LHS should take values of da for which it lies between +1 & -1. is Such dar represent wave like solutions $\psi(x) = e^{ikx} u_k(x)$. Other values of da are fosbidden.

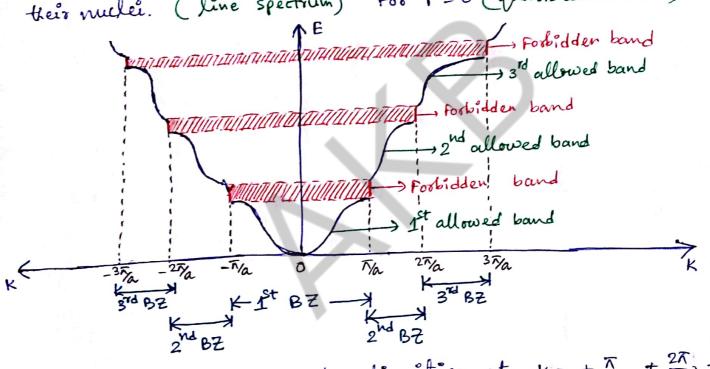


as $Ka \to [0, T]$, we $Ka \to [+1, -1]$ allowed boundaries coska = ± 1 or K = nT or $K = \frac{nT}{a}$.

As do increases, ρ sinda decreases, so the width of allowed energy bounds decreases in creases & forbidden energy regions become narrower. As ρ increases, width of allowed energy bounds decreases and for $\rho \to \infty$, they are infinitely thin I independent of ρ for $\rho \to \infty$, allowed do are points, da = $\pm n\pi$

 $n \propto x^2 = \frac{n^2 \pi^2}{a^2} = \frac{2mE}{\hbar^2} \qquad \text{i. } E = \frac{n^2 \pi^2 \hbar^2}{2ma^2} \neq E(K)$

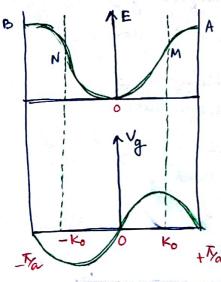
Everys level à discrete & the electron à completely bound lo their nuclei. (line spectrum) for P=0 (quasi-continuous)



 $E = \frac{t_1^2 k^2}{2m}$ will now have discontinuities at $k = \pm \frac{\pi}{a}$, $\pm \frac{2\pi}{a}$, $\pm \frac{2\pi}{a}$, $\pm \frac{2\pi}{a}$. These k values define the 1st, 2^{hd} , 3^{rd} , ... etc Brillouin Zones (BZ) The curves (bands) are horizontal be at bottom k top, parabolic near top k bottom with curvature in opposite direction, within a band, energy k periodic in k. as $cos(k + \frac{2\pi n}{a})a = coska k$ $\frac{2\pi n}{a}$ and $\frac{2\pi n}{a}$

Variation of Energy & relocity with wavevector

According to debroglie an electron moving with a velocity v is equivalent to a wave packet moving with group velocity = particle velocity $v_g = \frac{d\omega}{dk}$. As emergy of particle is $E = \hbar \omega$ or $\omega = \frac{E}{\hbar}$ $o \cdot v_{g} = \frac{d\omega}{d\kappa} = \frac{1}{h} \frac{dE}{d\kappa}$. Now we have for free electron $E = \frac{h \cdot k^{T}}{2m}$. $v_0 \frac{dE}{dK} = \frac{h}{m}K$, $v_0 = \frac{1}{h}\frac{dE}{dK} = \frac{h}{m}K = \frac{\rho}{m}$.



A from band theory Ed K2 but varies as shown.

Cerve is symmetric about OE axis with points of inflexion at MLN where de = maximum, so dk

as v (as s= \frac{1}{h} \frac{dE}{dK}). At points A, 0, B sope \frac{dE}{dE} = \frac{C}{C} \fra

rif inflexion point ±ko velocity is maximum (free eletron velocity)

Effective wan of an electron

The electrons in a crystal are not free but interact with the periodic potential of the lattice. So effective man is introduced so that that can be taken as free carriers of darge (electron or hole) in our calculation.

If election moves distance de so, electric field & in dt time then de= eEdx = eEvdt where v= dx = velocity Now $v = \frac{1}{h} \frac{dE}{dk}$. $dE = \frac{eE}{h} \frac{dE}{dk} dk$ or $\frac{dK}{dt} = \frac{eE}{h}$ Now the p is to dk = df = f = eE

Now
$$a = \frac{dv}{dt} = \frac{1}{t_1} \frac{d^2 E}{dk dt} = \frac{1}{t_1} \frac{d^2 E}{dk^2} \frac{dk}{dt} = \frac{1}{t_1} \frac{d^2 E}{dk^2} \frac{E}{t_1}$$

or $\frac{a}{F} = \frac{1}{t_1^2} \frac{d^2 E}{dk^2} = \frac{1}{m^*}$ (using $F = m^*a$)

$$m^* = \frac{t_1^2}{d^2 E}$$
. The ratio of rest man of free electron m to effective man in crystal in K -state i , $f_k = \frac{m}{m^*} = \frac{m}{t_1^2} \frac{d^2 E}{dk^2}$ which determines the extent to which electron can be thought free. Results of free electron theory can be applied to $f_k = \frac{1}{2m^*} \frac{d^2 E}{dk^2} \frac{dk}{dk^2}$.

Fand theory with $f_k = \frac{1}{2m^*} \frac{d^2 E}{dk^2} \frac{dk}{dk^2} \frac{dk}{dk^2}$.

Valence & Conduction band; foobidden band

The highest filled energy band which includes electrons shared in covalent bonds or electrons transferred in ionic bonds is known as valence band, denoted by Ev. When the number of valence electrons in one atom is less than the number of electrons to fill the outer orbit of other atom in solid, valence electrons are free to move to form free electron gas. A band of energy from 0 to Ef is move to form free electron band, denoted by Ec. The forbidden formed known as conduction band, denoted by Ec. The forbidden energy region where no electron can remain between Ey I Ec is the forbidde band, denoted by Eg.

We can distinguish conductors (metals), insulators, remiconductors on the basis of band theory. $f_k = \frac{m}{m^*} = \frac{m}{t^2} \frac{d^2E}{dk^2}$ that measures how much electron can take port in electric conduction.

Now for a 1-D lattice of periodicity L, $\psi(x+L) = \psi(x)$ i. $e^{ik(x+L)}u_k(x+L) = e^{ikx}u_k(x)$ Because of periodicity ux (x+L) = ux(x)

$$K = \frac{2\pi}{L}$$

$$e^{ik(\alpha+L)} = e^{ikx} \qquad k = \frac{2\pi n}{L} \qquad dk = \frac{2\pi}{L} dn, \quad dn = \frac{L}{2\pi} dk$$

du is the number of possible states between

K& K+dK. Since two electrons occupy each

state, effective no. of free electrons in staded

region is

egion is
$$N_{\text{eff}} = 2 \int_{-K_1}^{K_1} f_K dn = 2 \int_{-K_1}^{K_1} \frac{d^2 f_K}{dk^2} \frac{L}{2\pi} dK$$

$$= \frac{mL}{\pi h^2} \int_{-K_1}^{K_1} \frac{d^2E}{dk^2} dk = \frac{2mL}{\pi h^2} \int_{0}^{K_1} \frac{d^2E}{dk^2} dk = \frac{2mL}{\pi h^2} \left[\frac{dE}{dk} \right]_{0}^{K_1} = \frac{2mL}{\pi h^2} \left(\frac{dE}{dk} \right)_{K_1}^{K_2}$$

as $\frac{dE}{dK}$ at K=0=0. So Neff depends on $\left(\frac{dE}{dK}\right)_{K_1}$. When the band

is completely full so alop the band $\frac{dE}{dk} = 0$ is $\frac{Neff}{Neff} = 0$.

CW Dispersion relation for a 1D crystal of lattice constant a is

E(K) = Eo - d - 2 p cos ka where Eo, d, p combants. Find out the effective man of the electron at the bottom & top of the band.

We know
$$m^* = \frac{\hbar^2}{d^2 \epsilon} = \frac{\hbar^2}{2 \beta a^2 \cos \kappa a}$$

= cos R = -1, bottom of band, coska = coso = 1 Alop the band woo ka